Dual Bilateral Analog Switch / Digital Multiplexer

The NLX2G66 is a dual single pole, single throw (SPST) analog switch / digital multiplexer. This single supply voltage IC is designed with a sub-micron CMOS technology to provide low propagation delays (t_{pd}) and ON resistance (R_{ON}), while maintaining low power dissipation. This bi-lateral switch can be used with either analog or digital signals that may vary across the full power supply range from V_{CC} to GND.

Features

- Wide V_{CC} Operating Range: 1.65 V to 5.5 V
- OVT up to +5.5 V for Control Pin
- R_{ON}: Typically < 5 Ω at V_{CC} = 4.5 V and I_S = 32 mA
- Rail-to-Rail Input/Output
- High Speed, Typical t_{PD} < 1 ns at V_{CC} = 4.5 V and C_L = 50 pF
- High On-Off Output Voltage Ratio
- High Degree of Linearity
- Ultra-Small Pb-Free, Halide-Free, RoHS-Compliant Packages
- ESD Performance: > 5000 V HBM, > 400 V MM

Typical Applications

• Cell Phones, PDAs, MP3 and other Portable Media Players



Figure 1. Analog Symbol

PIN ASSIGNMENTS

UDFN8	UQFN8-0.5P	Description
1	7	1A
2	6	1B
3	5	2C
4	4	GND
5	3	2A
6	2	2B
7	1	1C
8	8	V _{CC}

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.



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FUNCTION TABLE

Control Input (C)	Switch
L	OFF
Н	ON

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

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Table 1. MAXIMUM RATINGS

Symbol	Rating		Value	Unit
V _{CC}	Positive DC Supply Voltage		-0.5 to +7.0	V
V _S	Switch Input / Output Voltage	(Pins 1A, 1B, 2A and 2B)	–0.5 to + V _{CC} + 0.5	V
VI	Digital Control Input Voltage	(Pins 1C and 2C)	-0.5 to +7.0	V
I _{ОК}	I/O port diode current		±50	mA
I _{IK}	Control input diode current		-50	mA
I _{I/O}	Continuous DC Current Through Analog Swit	ch	±100	mA
١L	Latch-up Current, (Above $V_{\mbox{CC}}$ and below \mbox{GN}	ID at 125°C)	±100	mA
Ts	Storage Temperature		−65 to +150	°C
V _{ESD}	ESD Withstand Voltage: Human Body M Machine Mode	Лоdel (НВМ) el (MM)	≥ 5000 > 400	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 2. RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Positive DC Supply Voltage		1.65	5.5	V
Vs	Switch Input / Output Voltage	(Pins 1A, 2A, 1B and 2B)	GND	V _{CC}	V
VI	Digital Control Input Voltage	(Pins 1C and 2C)	GND	5.5	V
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Transition Rise or Fall Time	$V_{CC} = < 3.0 V$	0	20	ns/V
		$V_{CC} = \ge 3.0 \text{ V}$	0	10	

Table 3. ELECTRICAL CHARACTERISTICS

					Guarant	teed Limit	:	
				25	°C	–55° to	125°C	
Symbol	Parameter	Condition	Vcc	Min	Max	Min	Max	Unit
V _{IH}	High–Level Input Voltage, Control Input		1.65 to 1.95			V _{CC} x 0.65		V
			2.3 to 5.5			V _{CC} x 0.7		
V _{IL}	Low-Level Input Voltage, Control Input		1.65 to 1.95				V _{CC} x 0.35	V
			2.3 to 5.5				V _{CC} x 0.30	
Ц	Input Leakage Current, Control Input	$V_{I} = V_{CC}$ or GND	5.5		±0.1		±1	μA
I _{S(ON)}	ON-State Switch Leakage Current	$\begin{array}{l} V_{IS} = V_{CC} \text{ or GND,} \\ V_{I} = V_{IH}, V_{OS} = Open \end{array}$	5.5		±0.1		±1	μA
I _{S(OFF)}	OFF-State Switch Leakage Current	$\begin{array}{l} V_{IS} = V_{CC} \text{ and } V_{OS} = \\ \text{GND, or } V_{IS} = \text{GND and} \\ V_{OS} = V_{CC} \text{ GND, } V_{I} = V_{IL}, \end{array}$	5.5		±0.1		±1	μΑ
I _{CC}	Quiescent Supply Current	$V_{I} = V_{CC}$ or GND	5.5		1.0		10	μA
ΔI_{CC}	Supply Current Change	$V_{I} = V_{CC} - 0.6$	5.5				500	μA
Cl	Control Input Capacitance		5				3.0	pF
C _{I/O(Off)}	Switch OFF Input / Output Capacitance	See Figure 3	5				6.0	pF
C _{I/O(On)}	Switch ON Input / Output Capacitance	See Figure 4	5				13	pF

Table 4. SWITCHING CHARACTERISTICS

				Guarante	ed Limit	
				–55° to	125°C	
Symbol	Parameter	Condition	V _{cc}	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay,	$C_L = 30 \text{ pF}, \text{ R}_L = 1 \text{ k}\Omega$	1.8		6.5	ns
	A to B, B to A		2.5		3.3	
		C_L = 50 pF, R_L = 500 Ω	3.3		2.5	
			5.0		2.2	
T _{EN}	Enable Time,	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8		10	ns
(^t PZL, ^t PZH)	C to Analog Output (A or B)	See Figure 6	2.5		6.5	
			3.3		5.5	
			5.0		4.9	
T _{DIS}	Disable Time,	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8		9.0	ns
([[] PLZI, [[] PHZ)	C to Analog Output (A or B)	See Figure 6	2.5		7.2	
			3.3		6.5	
			5.0		6.0	

Table 5. ANALOG SWITCH CHARACTERISTICS

					25°C	–55° to	125°C	
Symbol	Parameter	Conditions		Vcc	Тур	Min	Max	Unit
R _{ON}	On-Resistance	$V_{IS} = V_{CC}$ or GND,	I _S = 4 ma	1.65	12		30	Ω
		$v_{\rm I} = v_{\rm IH}$, see Figure 2	I _S = 8 ma	2.3	9		20	
			l _S = 24 ma	3.0	7.5		15	
			l _S = 32 ma	4.5	5.5		13	
R _{ON(peak)}	Peak On-Resistance	$V_{IS} = GND$ to V_{CC} ; $V_I = V_{IH}$,	I _S = 4 ma	1.65	74.5		220	Ω
		See Figure 2	I _S = 8 ma	2.3	20		75	
			l _S = 24 ma	3.0	11.5		25	
			l _S = 32 ma	4.5	7.5		17	
ΔR_{ON}	On-Resistance	$V_{IS} = GND$ to V_{CC} ; $V_I = V_{IH}$,	I _S = 4 ma	1.65			8.0	Ω
	Switches	See Figure 2	I _S = 8 ma	2.3			5.0	
			l _S = 24 ma	3.0			3.0	
			I _S = 32 ma	4.5			2.0	
BW	Bandwidth (f _{-3dB})	$R_L = 50 \Omega$, $C_L = 5 pF$,		1.65			> 270	MHz
		See Figure 8		2.3			> 270	
				3.0			> 270	
				4.5			> 270	

				25°C	
Symbol	Parameter	Conditions	v _{cc}	Тур	Unit
ISO _{Off}	Off-Channel	$R_{L} = 600 \Omega, C_{L} = 50 pF,$	1.65	-70	dB
	Isolation	See Figure 9	2.3	-70	
			3.0	-70	
			4.5	-70	
		$R_L = 50 \Omega, C_L = 5 pF,$	1.65	-60	
		See Figure 9	2.3	-60	
			3.0	-60	
			4.5	-60	
XTalk	Crosstalk	$R_L = 600 \Omega$, $C_L = 50 pF$,	1.65	-100	dB
	Between Switches	See Figure 10	2.3	-100	
			3.0	-100	
			4.5	-100	
		$R_L = 50 \Omega, C_L = 5 pF,$	1.65	-90	
		See Figure 10	2.3	-90	
			3.0	-90	
			4.5	-90	
	Feedthrough Noise,	$R_L = 600 \Omega, C_L = 50 pF,$	1.65	10	mV _{pp}
	Control to Switch	$I_{IN} = 1$ MHZ Square wave, $t_r = t_f = 2$ hs, See Figure 11	2.3	10	
			3.0	10	
			4.5	15	
THD	Total Harmonic	$C_L = 50 \text{ pF}, R_L = 50 \Omega,$	2.3	0.025	%
	DISION	See Figure 12	3.0	0.015	
			4.5	0.01	

Table 5. ANALOG SWITCH CHARACTERISTICS (continued)

Table 6. POWER DISSIPATION CHARACTERISTICS

				25°C	
Symbol	Parameter	Conditions	V _{cc}	Тур	Unit
C _{PD}	Power Dissipation	f = 10 MHz	1.65	8.0	pF
	Capacitance		2.3	8.9	
			3.0	9.6	
			4.5	10.9	

Table 7. DEVICE ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
NLX2G66AMUTCG (In Development)	UQFN8–0.5P, 1.6 mm x 1.6 mm (Pb–Free)	3000 / Tape & Reel
NLX2G66DMUTAG	UDFN8-0.5P, 1.95 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel
NLX2G66DMUTCG	UDFN8-0.5P, 1.95 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel
NLX2G66EMUTCG (In Development)	UDFN8–0.4P, 1.6 mm x 1.0 mm (Pb–Free)	3000 / Tape & Reel
NLX2G66FMUTCG (In Development)	UDFN8-0.35P, 1.45 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.







Figure 3. Maximum Off-Channel Leakage Current Test Set-Up



Figure 4. Maximum On–Channel Leakage Current Test Set–Up









Figure 5. Propagation Delay Test Set-Up











Figure 9. Off-Channel Feedthrough Isolation Test Set-Up



Figure 10. Crosstalk (between Switches)







Figure 12. Total Harmonic Distortion Test Set–Up







Figure 14. Propagation Delay, ON/OFF Control

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

UDFN8 1.6x1.0, 0.4P CASE 517BY ISSUE O



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.15	0.25	
D	1.60	BSC	
Е	1.00	BSC	
е	0.40	BSC	
L	0.25	0.35	
L1	0.30	0.40	

RECOMMENDED **SOLDERING FOOTPRINT***



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PACKAGE DIMENSIONS

UDFN8 1.45x1.0, 0.35P CASE 517BZ ISSUE O



NOTES:

NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.15	0.25	
D	1.45	BSC	
Е	1.00	BSC	
е	0.35	BSC	
L	0.25	0.35	
L1	0.30	0.40	

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PACKAGE DIMENSIONS

UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O



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- ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS.
- CONTROLLING DIMENSION: MILLIMETERS
 DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

BURRS AND MOLD FLA				
		MILLIMETERS		
	DIM	MIN	MAX	
	Α	0.45	0.55	
	A1	0.00	0.05	
	A3	0.13 REF		
	b	0.15	0.25	
	D	1.95 BSC		
	Е	1.00 BSC		
	е	0.50 BSC		
	L	0.25	0.35	
	L1	0.30	0.40	

RECOMMENDED SOLDERING FOOTPRINT*



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